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9. (New) A protection layer for a data recording medium, the protection layer comprising:
- a basic material; and
 - a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising magnesium oxide in a molar ratio with the basic material of 3% to 45% magnesium oxide.
10. (New) A protection layer for a data recording medium, the protection layer comprising:
- a basic material; and
 - a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising yttrium oxide in a molar ratio with the basic material of 10% to 80% yttrium oxide.
11. (New) A protection layer for a data recording medium, the protection layer comprising:
- a basic material; and
 - a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising gallium nitride in a molar ratio with the basic material of 1% to 30% gallium nitride.
12. (New) A protection layer for a data recording medium, the protection layer comprising:
- a basic material; and
 - a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising silicon nitride in a molar ratio with the basic material of 10% to 85% silicon nitride.
13. (New) A protection layer for a data recording medium, the protection layer comprising:
- a basic material; and

a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising aluminum nitride in a molar ratio with the basic material of 1% to 50% aluminum nitride.

B' 14. (New) A protection layer for a data recording medium, the protection layer comprising:
a basic material; and

a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising a silicon carbide in a molar ratio with the basic material of 5% to 50% silicon carbide.

15. (New) A protection layer for a data recording medium, the protection layer comprising:
a basic material; and

a compound having a thermal conductivity greater than or equal to 10 W/m.deg when in a bulk state, said compound comprising a titanium carbide in a molar ratio with the basic material of 10% to 85% titanium carbide.--

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